## NSN 5962-01-221-8010

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View Online at https://aerobasegroup.com/nsn/5962-01-221-8010 **Body Length:** 0.960 inches **Body Width:** Between 0.220 inches and 0.310 inches **Body Height:** 0.185 inches **Maximum Power Dissipation Rating:** 794.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and burn in and programmable and schottky and 3-state output **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 12 input **Case Outline Source And Designator:** D-6 mil-m-38510 **Terminal Surface Treatment:** Gold **Voltage Rating And Type Per Characteristic:** 7.0 volts power source **Time Rating Per Chacteristic:** 85.00 nanoseconds propagation delay time, low to high level output and 85.00 nanoseconds propagation delay time, high to low level output

## **Memory Device Type:**

Rom

**Memory Capacity:** 

Unknown

**Precious Material And Location:** 

Terminal surface option gold

**Precious Material:** 

Gold

**Test Data Document:** 

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

**Terminal Type And Quantity:** 

18 printed circuit

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	Life:

N/a

**Unit Of Measure:** 

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Demilitarization:

Yes - demil/mli

Fiig:

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